

	L #	Hits	Search Text	DBs
1	L1	32	chang\$1hyun near kim	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	L2	8	won\$1tae near choi	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	L3	2	"5769384".pn.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	L4	11	("5769384").URPN.	USPAT
5	L5	1	"6037643".pn.	USPAT
6	L6	6	("4173723" "4574249" "5149980" "5198660" "5256986" "5296696").PN.	US- PGPUB; USPAT; USOCR
7	L7	37435	voltage near2 step\$4	US- PGPUB; USPAT; USOCR

	L #	Hits	Search Text	DBs
8	L8	15719	photo\$1transistor or (photo near transistor)	US- PGPUB; USPAT; USOCR
9	L9	4689	(base or emitter) same 8	US- PGPUB; USPAT; USOCR
10	L10	4689	8 and 9	US- PGPUB; USPAT; USOCR
11	L11	227	7 and 9	US- PGPUB; USPAT; USOCR
12	L12	414418	capacitor or capacitance	US- PGPUB; USPAT; USOCR
13	L13	185	11 and 12	US- PGPUB; USPAT; USOCR
14	L14	837	9 same (constant or fix\$3)	US- PGPUB; USPAT; USOCR
15	L15	30	7 and 14	US- PGPUB; USPAT; USOCR
16	L16	25	15 and 12	US- PGPUB; USPAT; USOCR

	L #	Hits	Search Text	DBs
17	L17	1266	9 same 12	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
18	L18	110159	"250"/\$.ccls.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
19	L19	242	17 and 18	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
20	L20	11648	(emitter near3 voltage) same (constant or fix\$3 or maintain\$3)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	L #	Hits	Search Text	DBs
21	L21	296	20 and 9	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
22	L22	246	12 and 21	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
23	L23	48	22 and 18	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
24	L24	102046	(charg\$ or discharg\$3) near3 12	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	L #	Hits	Search Text	DBs
25	L25	34	23 and 24	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B